

TA9210D

12.5W CW 0.03 – 4.0 GHz GaN Power Transistor

Application Note: TA9210D EVB F

Application Note

200MHz~2700MHz

20V 50mA

Rev-1.3

List of Contents

- 1 General Description
- 2 TA9210D-EVB-F Board Details
- 3 TA9210D-EVB-F Bill of Material
- 4 TA9210D-EVB-F Biasing sequence
- 5 TA9210D-EVB-F Board Measurement Summary
- 6 TA9210D-EVB-F Board Measurement Results

1. General Description

The TA9210D is a broadband capable 12.5W GaN power transistor covering 30MHz to 2.7GHz frequency band with a single match. TA9210D is usable up to 4GHz. The input and output can be matched for best power and efficiency for the desired band.

The TA9210D is packaged in a compact, low-cost Quad Flat No lead (QFN) 3x6x0.75mm, 32 leads plastic package. TA9210D-EVB-F is tuned from 200MHz to 2700MHz.

2. TA9210D-EVB-F Board Details

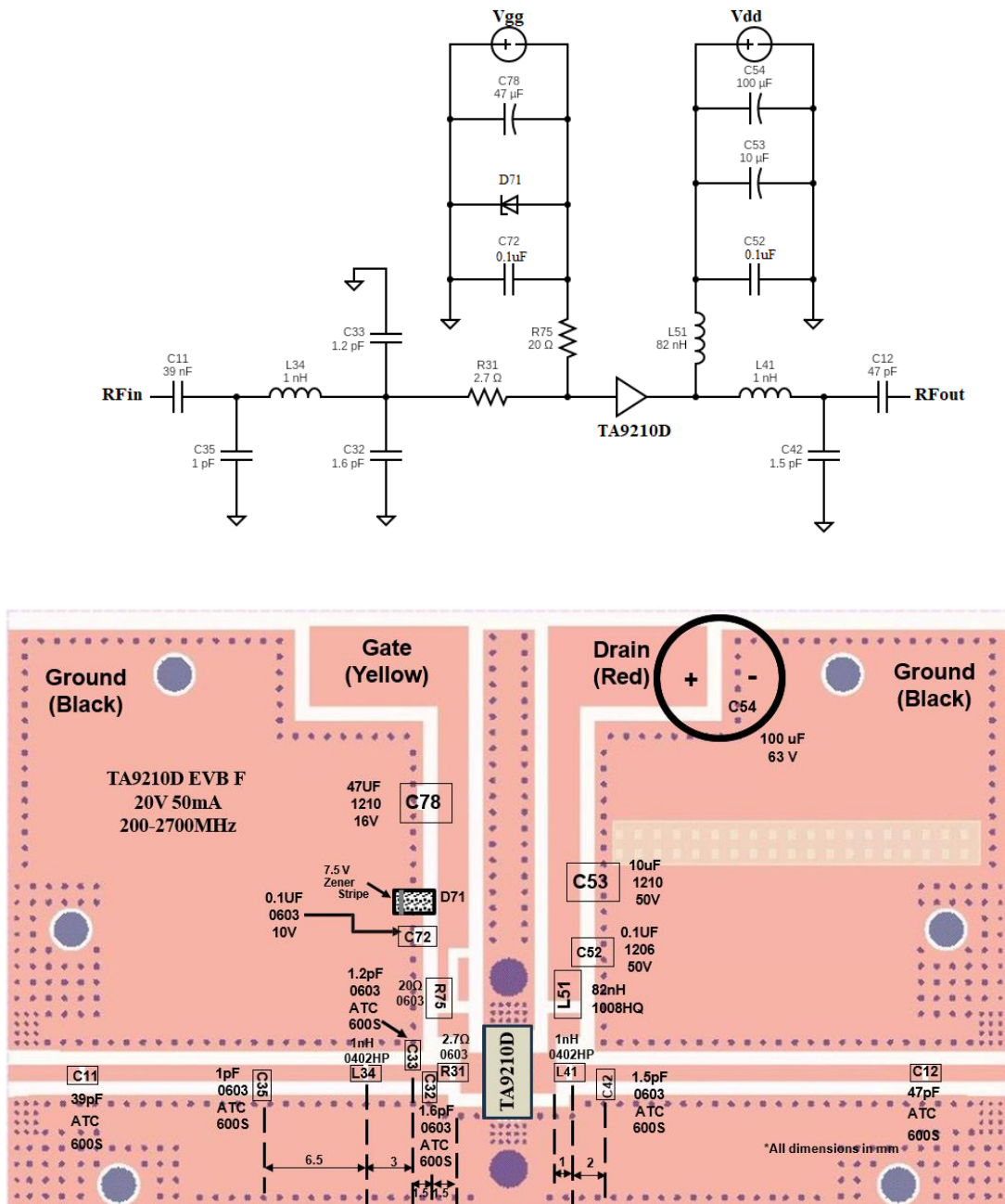


Figure 2.1 TA9210D-EVB-F 200MHz ~ 2700MHz Schematic and EVB Layout

3. TA9210D-EVB-F Bill of Material

| Component ID | Value | Manufacturer | Recommended Part Number |
|--------------|------------------------------------|-------------------|-------------------------|
| C11 | 39 pF | AVX | 600S390FT250XT |
| C12 | 47 pF | AVX | 600S470FT250XT |
| R31 | 2.7 Ω | Vishay | CRCW06032R70FKEAHP |
| C32 | 1.6 pF | AVX | 600S1R6BW250XT |
| C33 | 1.2 pF | AVX | 600S1R2BW250XT |
| L34,L41 | 1 nH | Coil craft | 0402HP-1N0XJRW |
| C35 | 1 pF | AVX | 600S1R0BW250XT |
| C42 | 1.5 pF | AVX | 600S1R5BW250XT |
| L51 | 82 nH | Coil craft | 1008HQ-82NXGLC |
| C52 | 0.1 uF, 50V | Murata | GRM31C5C1H104JA01L |
| C53 | 10uF,50V | Murata | GRM32ER71H106KA12L |
| C54 | 100 uF, 63V | Nichicon | UPW1J101MPD1TD |
| D71 | 7.5 V Zener | On Semiconductor | SZMMSZ5236BT1G |
| C72 | 0.1 uF, 10V | AVX | 0603ZC104K4T2A |
| R75 | 20 Ω | Vishay | CRCW060320R0FKEAHP |
| C78 | 47 uF, 16V | Murata | GRM32ER61C476ME15L |
| Q1 | 12.5Watt power transistor | Tagore Technology | TA9210D |
| PCB | Rogers RO4350B, 20mils, 2oz copper | | |

Table 3.1 TA9210D-EVB-F BOM

4. TA9210D-EVB-F Biasing Sequence

| Turn ON Device | Turn OFF Device |
|--|--|
| <ol style="list-style-type: none"> 1. Set V_G to -5V 2. Set V_D to +20V 3. Adjust V_G to reach required I_{DQ} current 4. Apply RF power | <ol style="list-style-type: none"> 1. Turn RF power off 2. Turn off V_D 3. Turn off V_G |

Table 4.1 TA9210D-EVB-F Bias and Sequencing

5. TA9210D-EVB-F Board Measurement Summary

| Frequency (MHz) | S21 Gain(dB) | S11 (dB) | S22 (dB) | Psat (dBm) | PAE (%) @Psat |
|-----------------|--------------|----------|----------|------------|---------------|
| 200 | 18.9 | -6.9 | -7.4 | 37.2 | 75 |
| 500 | 18.1 | -6.8 | -4.6 | 37.8 | 66 |
| 1000 | 16.6 | -5.9 | -3.7 | 38.5 | 58 |
| 1500 | 15.8 | -6.7 | -3.7 | 38.2 | 45 |
| 2000 | 14.4 | -5.9 | -6.3 | 39.5 | 40 |
| 2700 | 13.5 | -9.9 | -15.6 | 38.2 | 50 |

Table 5.1 TA9210D-EVB-F 20V 50mA Electrical Characteristics Summary

6. TA9210D-EVB-F Test Results

All the tests are carried out at room temperature.

6.1. S parameters

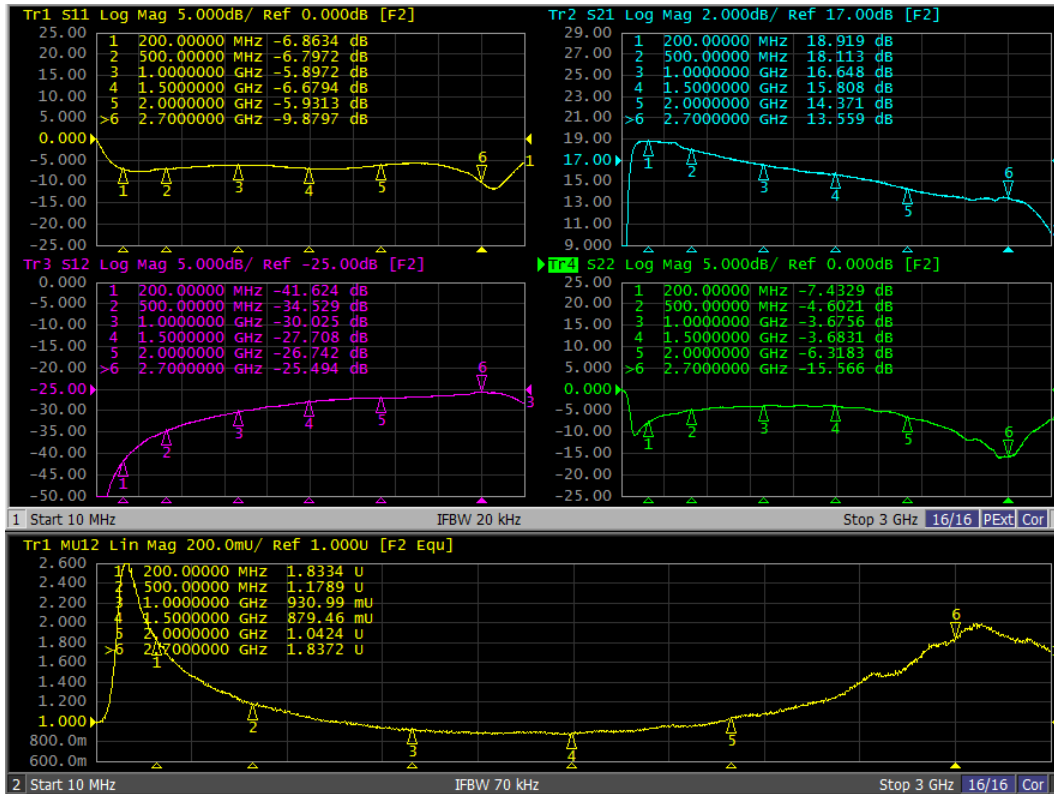


Figure 6.1.1. S parameters of TA9210D-EVB-F 20V 50mA

6.2. Large Signal Test Results

Gain and PAE Vs P_{OUT} data [V_d=20V, I_{DQ}=50mA, CW]

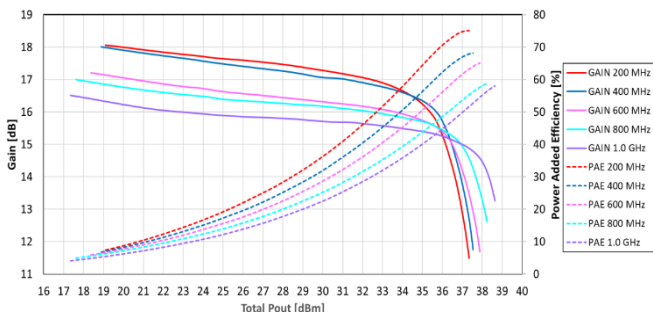


Figure 6.2.1. Gain and PAE vs P_{OUT} of TA9210D-EVB-F for 20V 50mA 200M-1GHz

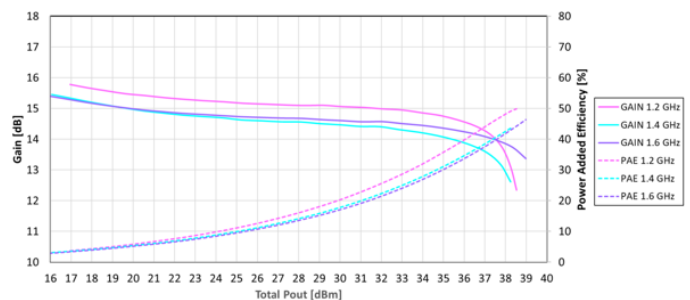


Figure 6.2.2. Gain and PAE vs P_{OUT} of TA9210D-EVB-F for 20V 50mA 1.2G-1.6GHz

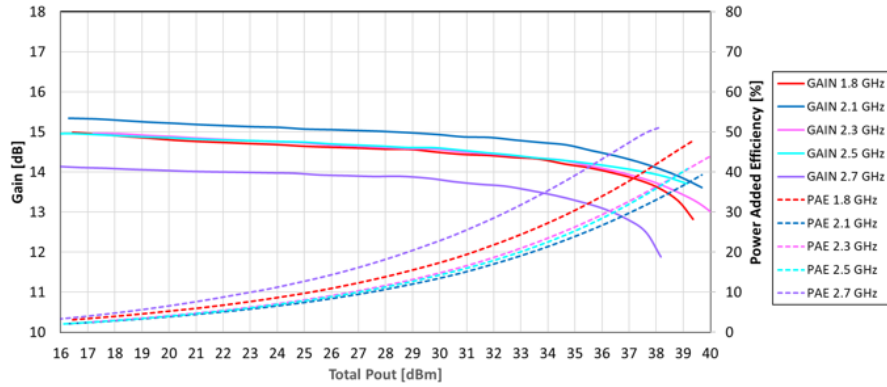


Figure 6.2.3. Gain and PAE vs P_{OUT} of TA9210D-EVB-F for 20V 50mA 1.8G-2.7GHz

6.3. ACPR and AACPR Test Results

Bias :20V 50mA

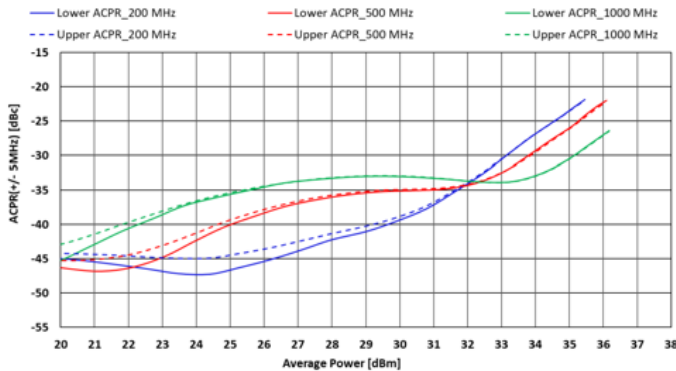


Figure 6.3.1. ACPR vs P_{OUT} of TA9210D-EVB-F for 20V 50mA 200M-1GHz

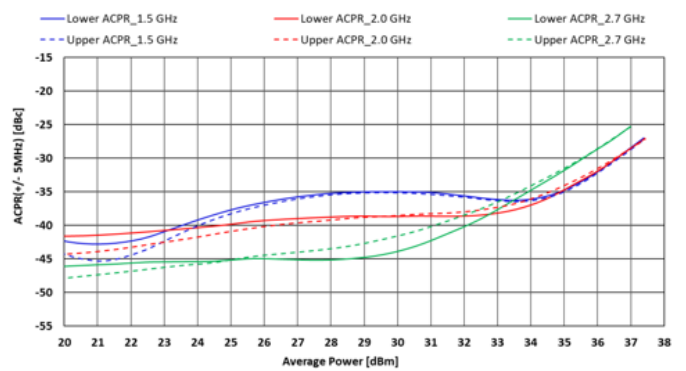


Figure 6.3.2. ACPR vs P_{OUT} of TA9210D-EVB-F for 20V 50mA 1.5G-2.7GHz

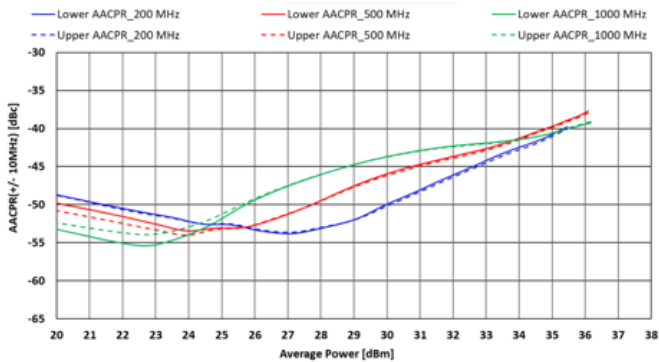


Figure 6.3.3. AACPR vs P_{OUT} of TA9210D-EVB-F for 20V 50mA 200M-1GHz

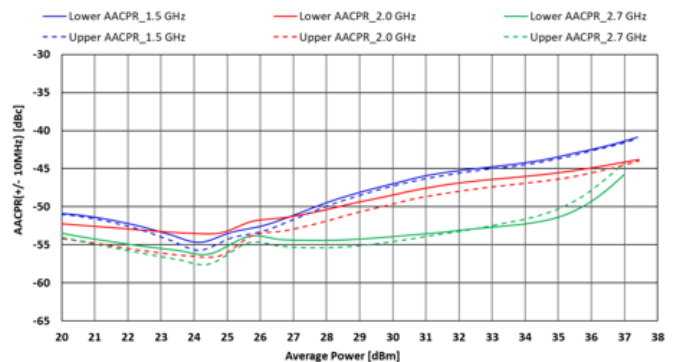


Figure 6.3.4. AACPR vs P_{OUT} of TA9210D-EVB-F for 20V 50mA 1.5G-2.7GHz

Bias :20V 600mA

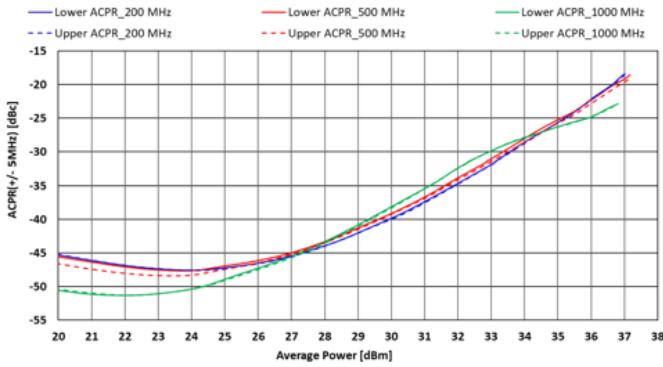


Figure 6.3.5. ACPR vs P_{OUT} of TA9210D-EVB-F for 20V 50mA 200M-1GHz

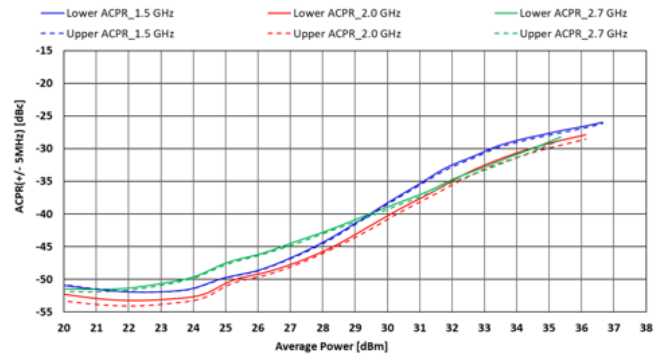


Figure 6.3.6. ACPR vs P_{OUT} of TA9210D-EVB-F for 20V 50mA 1.5G-2.7GHz

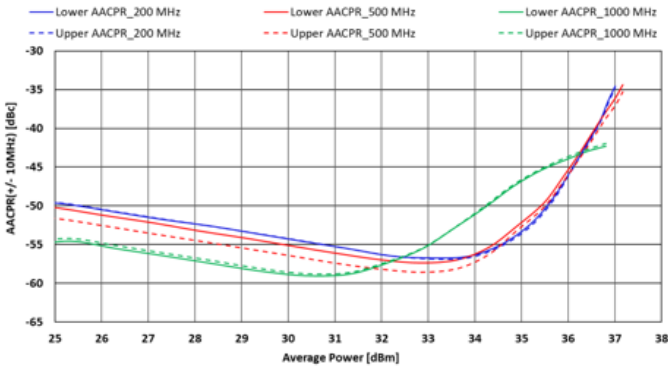


Figure 6.3.7. AACPR vs P_{OUT} of TA9210D-EVB-F for 20V 50mA 200M-1GHz

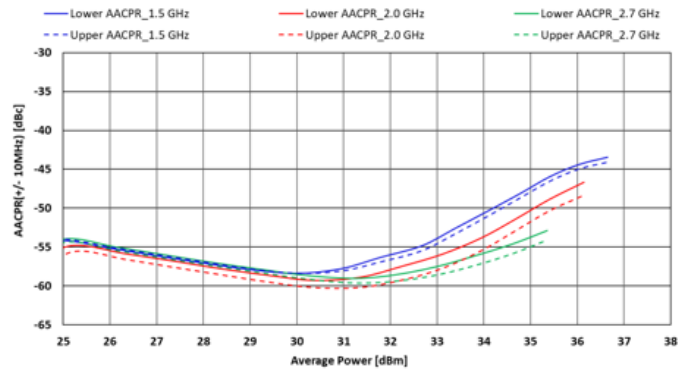


Figure 6.3.8. AACPR vs P_{OUT} of TA9210D-EVB-F for 20V 50mA 1.5G-2.7GHz

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